

Non-Synchronous PWM Boost Controller for LED Driver



General Description

The FP7208B is boost topology switching regulator for LED driver. It provides built-in gate driver pin for driving external N-MOSFET. The non-inverting input of error amplifier connects to a 0.2V reference voltage. It has programmable soft start time set by external capacitor, and over voltage protection set by external resistor. The LED current can be adjusted by an external signal connecting to the EN pin. EN pin accepts either a DC voltage or a PWM signal. The PWM signal filter components are contained within the chip.

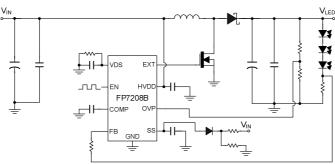
Features

- > Start-up Voltage: 2.5V
- Wide Supply Voltage Operating Range: 4.5V to 24V
- Precision Feedback Reference Voltage: 0.2V (Max.)
- > Analog and Digital Dimming Control
- > Shutdown Current: 6µA (Max.)
- Internal Fixed Switching Frequency: 300KHz
- > Programmable Soft Start Function (SS)
- > Programmable Over Voltage Protection (OVP)
- Over Temperature Protection (OTP)
- Package: SOP-8L(EP)

Applications

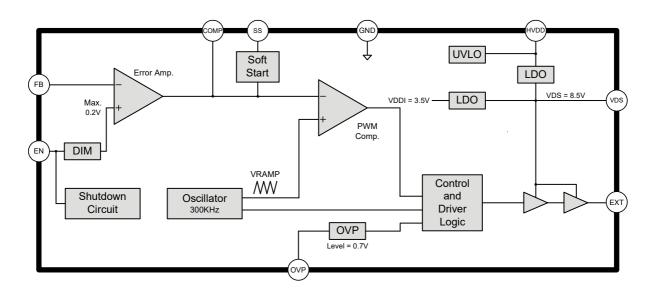
- > LED Module
- Display Backlight
- Car Lighting
- Portable LED Lighting

Typical Application Circuit



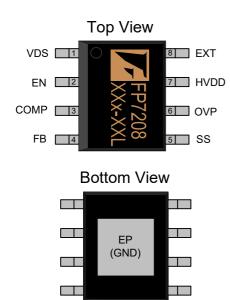


Function Block Diagram



Pin Descriptions

SOP-8L (EP)

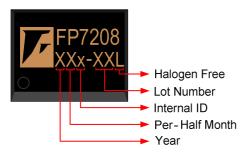


Name	No.	1/0	Description	
VDS	1	Р	Power Supply for Internal Control Circuits and Gate Drivers	
EN	2	I	Enable and Dimming Control	
COMP	3	0	Compensation	
FB	4	I	Error Amplifier Inverting Input	
SS	5	I	Soft Start Programming	
OVP	6	I	Over Voltage Protection	
HVDD	7	Р	IC Power Supply	
EXT	8	0	Gate Driver Output	
GND	9	Р	IC Ground (Exposed PAD) – Must Connect to Ground	



Marking Information

SOP-8L(EP)



Halogen Free: Halogen free product indicator

Lot Number: Wafer lot number's code
Internal ID: Internal Identification Code

Per-Half Month: Production period indicator in half month time unit

For Example : $A \rightarrow First Half Month of January$

 $\begin{array}{ll} B \ \to Second \ Half \ Month \ of \ January \\ C \ \to First \ Half \ Month \ of \ February \\ D \ \to Second \ Half \ Month \ of \ February \\ \end{array}$

Year: Production year's last digit



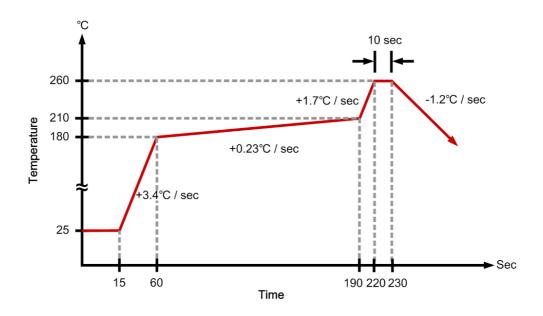
Ordering Information

Part Number	Operating Temperature	Package	MOQ	Description
FP7208BXR-G1	-25°C ~ 85°C	SOP-8L(EP)	2500EA	Tape & Reel

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	HVDD	-	0	-	25	٧
VDS,EXT Voltage	-	-	0	-	16	V
Others Pin Voltage	-	-	0	-	6	V
Thermal Resistance (Junction to Ambient)	θја	SOP-8L (EP)	-	-	+60	°C / W
Thermal Resistance (Junction to Case)	θ_{JC}	SOP-8L (EP)	-	-	+10	°C / W
Junction Temperature	TJ	-	-	-	+150	°C
Operating Temperature	T _{OP}	-	-25	-	+85	°C
Storage Temperature	T _{ST}	-	-65	-	+150	°C
Lead Temperature	-	(soldering, 10 sec)	-	-	+260	°C

IR Re-flow Soldering Curve



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Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	HVDD	-	4.5	-	24	V
Operating Temperature Range	T _A	Ambient Temperature	-25	-	+85	°C

DC Electrical Characteristics (HVDD=12V, T_A=25°C, unless otherwise specified)

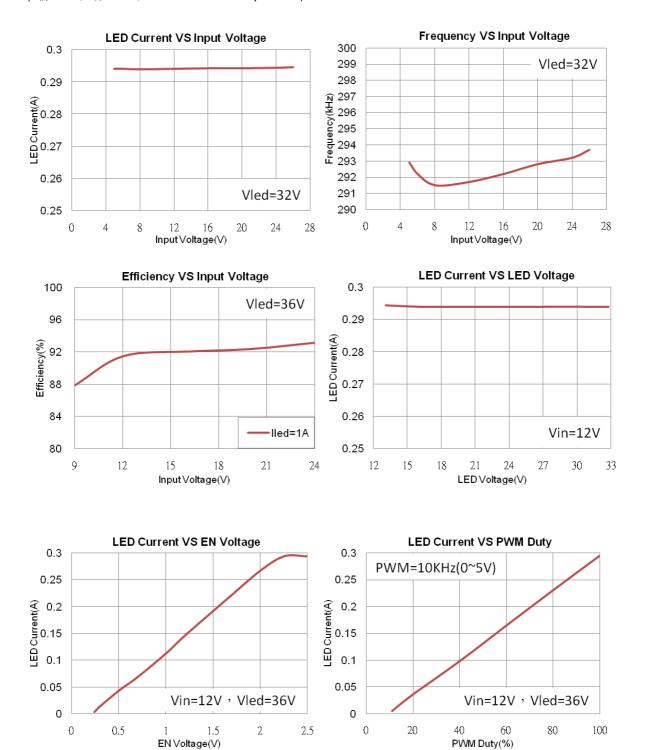
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
System Supply Input				•		
Start-up Voltage		-	2.5			V
Input Supply Range	HV _{DD}	-	4.5	-	24	٧
Under Voltage Lockout	V _{UVLO}	-	-	2.2	-	V
UVLO Hysteresis	-	-	-	0.1	-	V
Average Current	Icc	FB=0V, Switching	-	5	-	mA
Quiescent Current	Icc	FB=0.55V, No Switching	-	245	-	μΑ
Shutdown Current	Icc	V _{EN} =GND	-	-	6	μΑ
Input Supply Voltage	V _{DS}	HV _{DD} =12V, I _{DS} =0A	-	8.5	-	V
Oscillator						
Operation Frequency	fosc	FB=0V	250	300	350	KHz
Maximum Duty Ratio	%	FB=0V	-	90	-	%
Soft Start						
Soft-Start bias Current	Iss	V _{ss} =0V	-	1.5	-	μΑ
Reference Voltage						
Feedback Voltage	V _{FB}	Connect EN to VDS with a 100kΩ, EN≒3V	0.197	0.203	0.209	٧
Enable Control						
Enable Voltage	V _{EN}	-	0.20	0.25	0.30	٧
Shutdown Voltage	V _{EN}	-	-	-	0.07	٧
External Transistor Connec	tion curre	ent				
EXT Pull-UP Resistance	R _{EXTH}	V _{DS} =8.5V	-	1	-	Ω
EXT Pull-Down Resistance R _{EXTL}		V _{DS} =8.5V	-	1	-	Ω
Over Voltage Protection						
OVP Threshold V _{OVP}		-	0.65	0.70	0.75	٧
Thermal Shutdown						
Thermal Shutdown Threshold	T _{TS}	-	-	+150	-	°C

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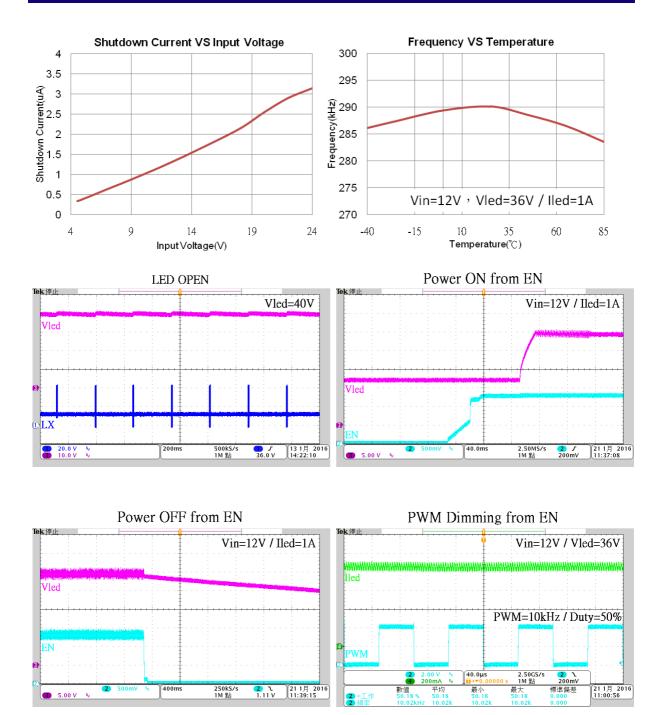


Typical Operating Characteristics

 $(V_{IN}=12V, T_A=25^{\circ}C, unless otherwise specified)$









Function Description

Operation

The FP7208B is voltage mode boost controller for LED driver. It operates with pulse width modulation (PWM), and changes to PSM mode when output is light load. The internal resistive divider provides 0.2V reference for the error amplifier, which can reduce the power dissipation in the current sense resistor.

Soft Start Function

Soft start time is programmable to connect capacitor between SS pin to ground. After the IC is enabled, the output of error amplifier is clamped by the internal soft-start function, which causes PWM pulse width increasing slowly and thus reducing input surge current during power on. The soft start bias current is 1.5μ A.

Enable Mode / Shutdown Mode

Drive the EN pin to ground to shutdown the IC. Shutdown mode forces to turn off all internal circuitry, and reduces the HVDD supply current to 6uA (max). EN pin rising threshold is 0.25V.

DC Dimming Control

The DC voltage is connected to EN pin adjust the voltage to change feedback voltage (V_{FB}). EN internal voltage is clamped in 2.25V (V_{EN}) when external voltage exceeds 2.25V. The valid EN voltage is from 0.25V to 2.25V. The maximum feedback voltage is 0.2V. The LED current (I_{LED}) can be calculated using formula below.

$$V_{_{FB}} = \frac{V_{_{EN}} - 0.25V}{10}$$
 , $I_{LED} = \frac{V_{_{FB}}}{R_{_{S}}}$

PWM Dimming Control

The PWM signal is connected to EN pin adjust duty cycle to change feedback voltage (V_{FB}). EN internal voltage is clamped in 2.25V (V_{PWM}) when external PWM voltage exceeds 2.25V, and internal filter regulates PWM signal become a DC voltage. The DC voltage is valid from 0.25V to 2.25V. The PWM signal is recommended above 10KHz. The LED current (I_{LED}) can be calculated using formula below.

$$V_{FB} = \frac{V_{PWM} \times Duty - 0.25V}{10} \quad I_{LED} = \frac{V_{FB}}{R_s}$$



FB Voltage Setting

How to set FB voltage when LEDs don't need dimming control. The resistor $100K\Omega$ is connected between VDS and EN, which cause EN voltage more than 2.25V. The FB voltage is constant 0.2V.

Over Voltage Protection

The gate driver signal is turned off when OVP pin voltage exceeds 0.7V. The voltage (V_{OVP}) can be calculated using formula below, and circuit is shown as below.

$$V_{OVP} = 0.7V \left(1 + \frac{R3}{R4}\right)$$

Application Information

Inductor Selection

Inductance value is decided based on different condition. $4.7\mu H$ to 68uH inductance value is recommended for general application circuit. There are three important inductor specifications, DC resistance, saturation current and core loss. Low DC resistance has better power efficiency.

Capacitor Selection

The output capacitor is required to maintain the DC voltage during switching. Low ESR capacitors are preferred to reduce the output voltage ripple. Ceramic capacitor of X5R and X7R are recommended, which have low equivalent series resistance (ESR) and wider operation temperature range.

Diode Selection

Schottky diodes with fast recovery times and low forward voltages are recommended. Ensure the diode average and peak current rating exceed the average output current and peak inductor current. In addition, the diode's reverse breakdown voltage must exceed the output voltage.

LED Current Programming

The LED current is set by a resistor from the FB pin to ground. The LED current is:

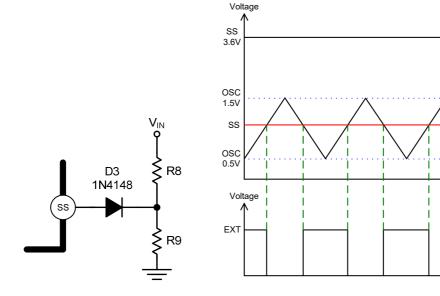
$$I_{\text{LED}} = \frac{V_{\text{FB}}}{R_{\text{s}}}$$

SS Voltage Drop EXT Duty Limit



Input Current Limit Setting

The SS voltage is adjusted using a resistive voltage divider connected from input voltage to D3 cathode, D3 Anode connects to SS pin. The input occur inrush current to cause input voltage drop off then SS voltage also drop less than 1.5V, PWM duty of EXT pin can be limited, which reduces inrush current to protect switching MOSFET. The level of internal oscillator is from 0.5V to 1.5V. D3 is unconnected the SS voltage is 3.6V. The circuit and detailed figure are shown as below.

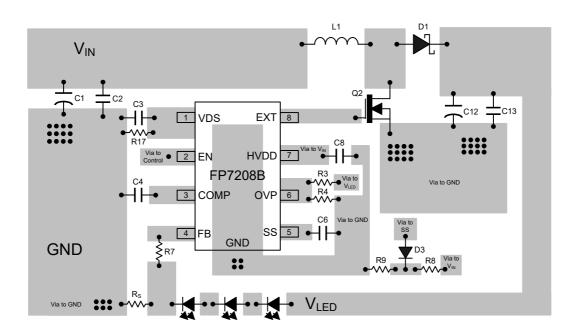


→ Time



Layout Considerations

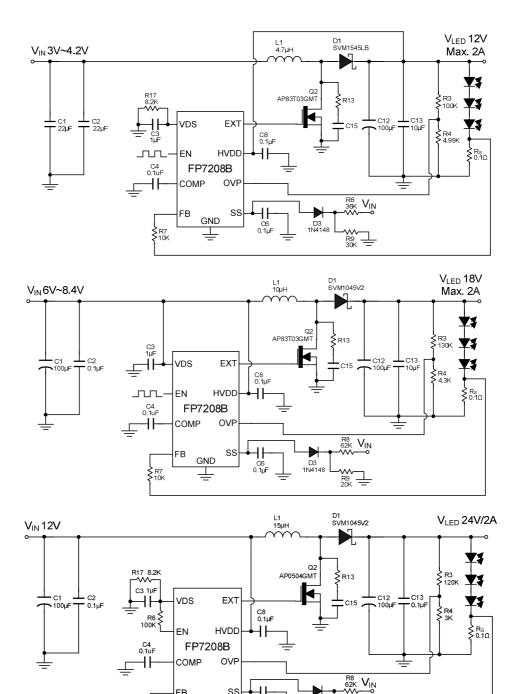
- 1. The power traces, consisting of the GND trace, the MOS drain trace and the V_{IN} trace should be kept short, direct and wide.
- 2. Layout switching node MOS drain, inductor and schottky diode connection traces wide and short to reduce EMI.
- 3. Place C8 nearby HVDD pin as closely as possible to maintain input voltage steady and filter
- 4. The sense resistor R_S must be connected to FB pin directly and as closely as possible.
- 5. FB is a sensitive node. Please keep it away from switching node, MOS drain.
- 6. The GND of the Q2, C1, C2, C12 and C13 should be connected close and together directly to a ground plane.
- 7. The output capacitor C12 and C13 should be connected close and together directly to the ground of Q2.



Suggested Layout



Application Information



Note:

1. The X5R and X7R of ceramic capacitors are recommended to choose.

\$R7 \$10K

2. R13 and C15 are added for reducing EMI (Electromagnetic Interference).

GND

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3. R17 must be connected between VDS pin and ground.

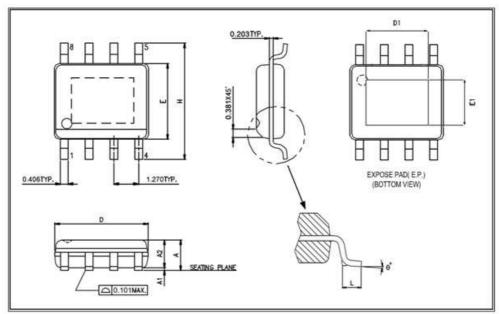
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₩ 8.2K =



Package Outline

SOP-8L (EP)



UNIT: mm

Symbols	Min. (mm)	Max. (mm)
Α	1.30	1.70
A1	0	0.15
A2	1.25	1.55
D	4.70	5.10
E	3.80	4.00
Н	5.80	6.20
L	0.40	1.27

Exposed PAD Dimensions:

Symbols	Min. (mm)	Max. (mm)
D1	2.60	3.45
E1	1.90	2.56

Note:

- 1. Package dimensions are in compliance with JEDEC outline: MS-012 AA.
- 2. Dimension "D" does not include molding flash, protrusions or gate burrs.
- 3. Dimension "E" does not include inter-lead flash or protrusions.

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